

Wen-li Wu talks about advances in x-ray-based semiconductor metrology

Qinghuang Lin*
JM3 Associate Editor

ABSTRACT. JM3 Associate Editor Qinghuang Lin interviews Wen-li Wu, retired from the National Institute of Standards and Technology. With R. Joseph Kline, Ronald L. Jones, Hae-Jeong Lee, Eric K. Lin, Daniel F. Sunday, Chengqing Wang, Tengjiao Hu, and Christopher L. Soles, Wu is the lead author of “[Review of the key milestones in the development of critical dimension small angle x-ray scattering at National Institute of Standards and Technology](#),” a review paper in the Special Section on 3D Metrology in the July–September 2023 issue of the *Journal of Micro/Nanopatterning, Materials, and Metrology*.

[DOI: [10.1117/1.JMM.22.3.030701](https://doi.org/10.1117/1.JMM.22.3.030701)]



Dr. Wen-li Wu, retired from the National Institute of Standards and Technology, authored a JM3 review paper on advances in x-ray-based semiconductor metrology. Watch the interview at <https://doi.org/10.1117/1.JMM.22.3.030701.s1>

*Address all correspondence to Qinghuang Lin, qinghuang.lin@gmail.com

© The Authors. Published by SPIE under a Creative Commons Attribution 4.0 International License. Distribution or reproduction of this work in whole or in part requires full attribution of the original publication, including its DOI.